

EECS 270 Group Homework 4

Due Friday, June 1st @9:45am, half credit if turned in by June 1st @4pm.

Name: _____ unique name: _____

Name: _____ unique name: _____

Name: _____ unique name: _____

This is a group assignment; all of the work should be that of only your group members. Assignments that are unstapled, lack a cover sheet, or are difficult to read will lose at least 50% of the possible points and we may not grade them at all.

It is expected that each group member contributed to the assignment; non-contributing members should not have their name on this document. This assignment is worth about 1% of your grade in the class and is graded out of 30 points. Remember you may drop one group assignment.

There are 100 points on this assignment. It will be graded out of 30 by taking your score out of 100 and subtracting 70 (minimum 0). You should also be aware that it will be graded more strictly than the exam (you have more time and more people!) Also, I may use the best answers as the key. If I do use your group's answers as the key, I'll give your group 3 extra credit points on this assignment.

Scores:

Problem #	Points
1	/12
2	/5
3	/12
4	/14
5	/10
6	/12
7	/10
8	/10
9	/15
Total	/100

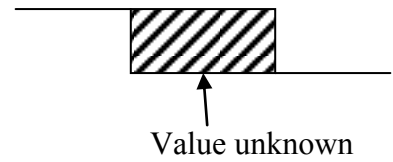
Short Answer/Fill in the blank

1. Fill in each blank or circle the best answer. [12 points, -2 per wrong or blank answer, min 0]

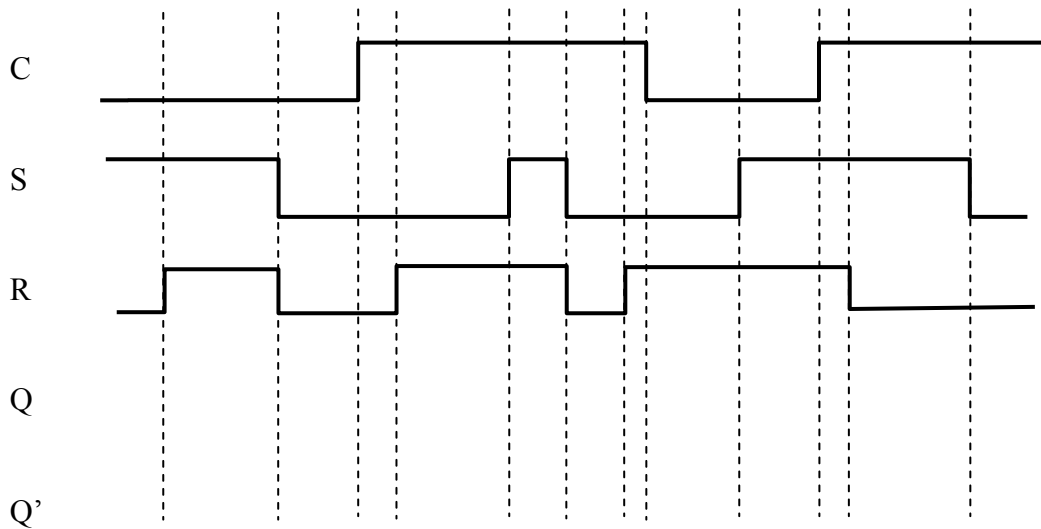
- a. The 5-bit 2's complement number representation of -4 is _____.
- b. 10001, when treated as a 5-bit signed-magnitude number, has a decimal representation of _____.
- c. Individual DRAM cells are typically ***larger/smaller*** than SRAM cells and in general DRAM cells are ***faster/slower*** than SRAM cells.
- d. Say you want to perform "conditional negation." That is, you have an input x and an input y, and if x is 0 the output should be y, but if x is 1 the output should be !y. If you were going to implement this as a single gate, you'd use a(n) _____ gate.
- e. Consider a memory device that has 256 addresses each 16 bits in size. If this was made out of a square memory (equal number of rows and columns in the memory device) the row decoder would have _____ inputs while the column MUX would have _____ selection bits.
- f. The canonical product-of-sums representation of $\overline{(A+B)}$ is _____.
- g. Say a tri-state device was outputting a value of "HiZ" and that value was driven to the input of a two-input AND gate where the other input was a "1". The AND gate's output would be "0" / "1" / "HiZ" / unknown.

2. Using the *rules of logic*, convert $\neg(A+\neg C)*(A*C)$ into a *minimal* sum-of-products form. Provide the name of the rule used for each step. **[5 points]**

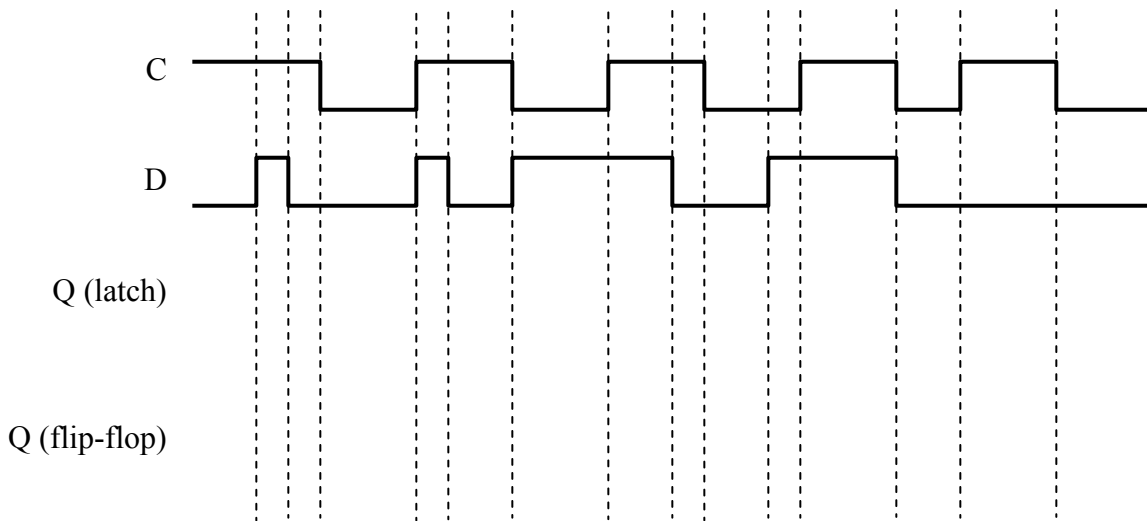
3. Complete the following timing diagrams. If the value is unknown (or oscillating) at some point, clearly indicate that with hashes (as shown). Each Q value will be graded as either right or wrong (no partial credit on a given Q value).



a) Complete the timing diagram below for an SR latch with enable. [6 points]



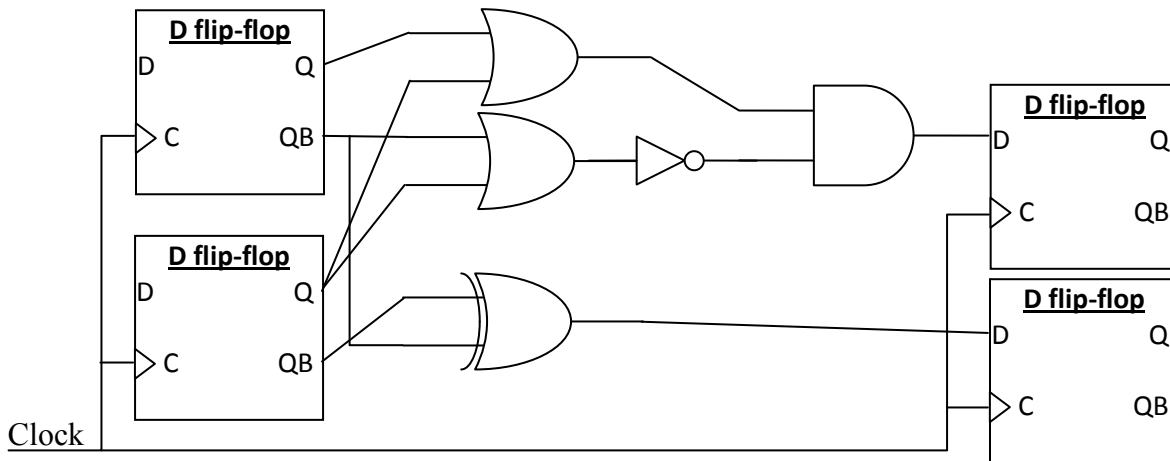
b) Complete the timing diagram below for both a D latch and a D flip-flop. [6 points]



4. Say you have the following values associated with the process you are using (notice the hold and set-up times are not specified). Assume you intend to clock this circuit at 50MHz.

DFF:		Min	Max
	<i>Clock to Q</i>	2ns	3ns
	<i>Set-up time</i>	?? ns	
	<i>Hold time</i>	?? ns	

		Min	Max
OR/AND		2ns	5ns
NOT		1ns	2ns
XOR		2ns	7ns

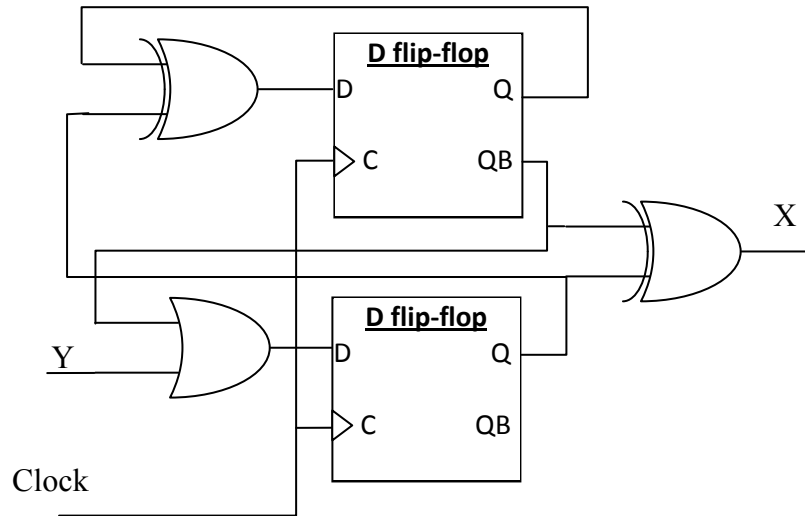


- a. Assuming you want a reliable circuit, what is the highest value the flip-flop could have for a hold time? Show your work. **[4 points]**
- b. Assuming you want a reliable circuit, what is the highest value the flip-flop could have for a setup time? Show your work. **[4 points]**

(Problem continued on the next page)

5. Draw the state-transition diagram that describes the following state-machine. Assume the initial state is when the flip-flops both have a value of 0. Show all state (even if a given state is unreachable). *Show your work.*

[10 points]



6. Design a state-transition diagram for a state machine with two inputs, A and B, and two outputs, “Y” and “Z”. Y should be a “1” if A and B were the same (equal) in the previous cycle. Z should be a “1” if A and B were the same two cycles ago (the cycle previous to the previous cycle). For example, the following input:

A: 010010001

B: 001011001

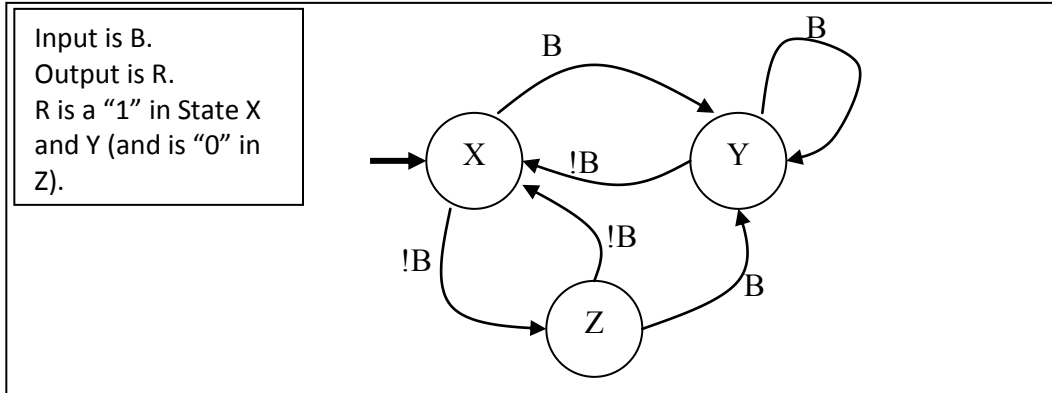
Would generate this output:

Y: 010011011

Z: 001001101

Your answer must have no more than 7 states. [**12 points**; 9 points for a correct answer; 3 for a correct *and* minimal-state answer]

7. Design a state machine which implements the following state transition diagram. Assign state bits $S[1:0]$ as 11 for state X, 01 for state Y, and 10 for state Z. You are to assume that you will never reach the state $S[1:0]=00$, so you don't care what happens in that case. You must show your work to get any credit! You only need to compute the next state and output logic, you don't need to draw the gates or flip-flops! Place your answer where shown. [10 points]

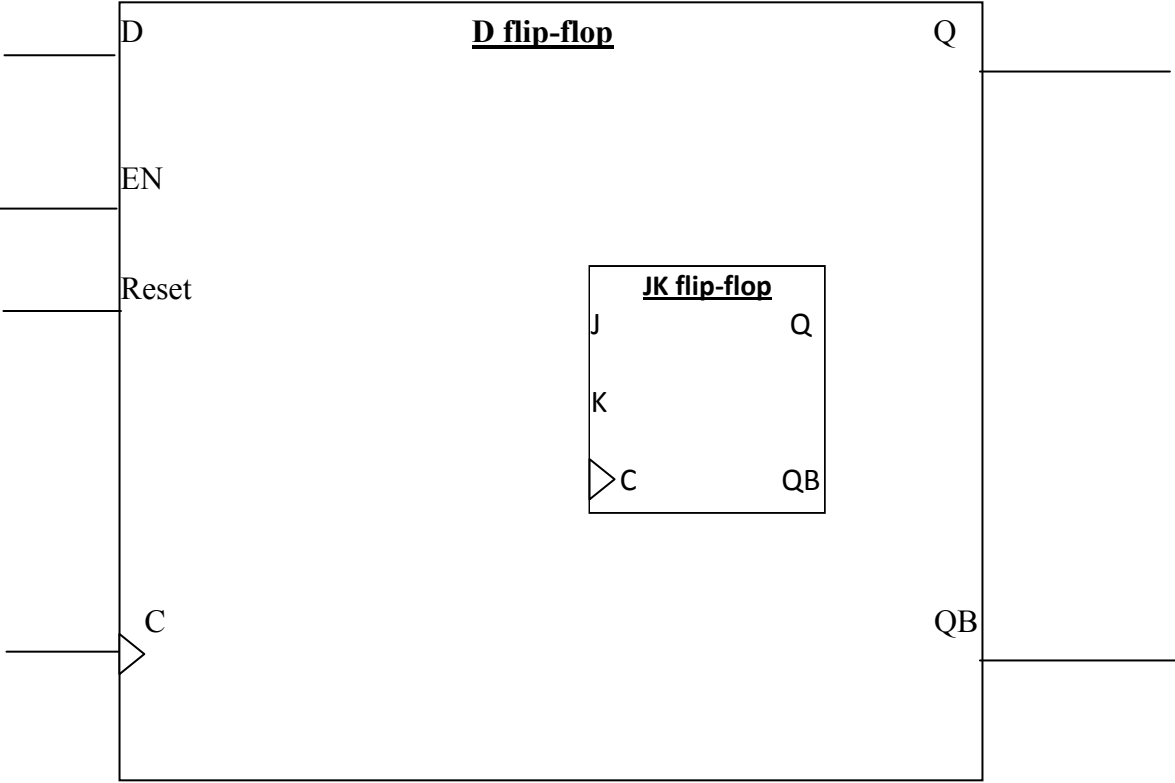


NS1= _____

NS0= _____

R= _____

8. Build a D flip-flop with enable and reset using only a JK flip-flop (without enable or reset) and standard gates. [10 points]



9. Using only the devices listed below, design a circuit which takes two 4-bit signed-magnitude numbers (X[3:0] and Y[3:0]) and outputs the smaller of the two, named OUT[3:0].

In your design you may use the following devices (as well as freely using “0” and “1” as a inputs as desired)

- AND, OR, and XOR gates (any number of inputs)
- Inverters
- 2 to 1 MUXes
- 4-bit *unsigned* comparator
- 8 to 4 MUXes
- 16 to 4 priority encoder

You must clearly label any device you use (other than gates and inverters) and your design should be clear enough that someone else could understand how everything was to be connected. Your grade will be based in part upon the efficiency of your design. **[15]**